



浙江芯芯电子有限公司
ZHEJIANG XINXIN ELECTRICAL CO., LTD.

产品规格书

Specification of Products

产品名称：平板型

产品型号：200A

浙江芯芯电子有限公司

ZHEJIANG XINXIN ELECTRICAL CO., LTD.

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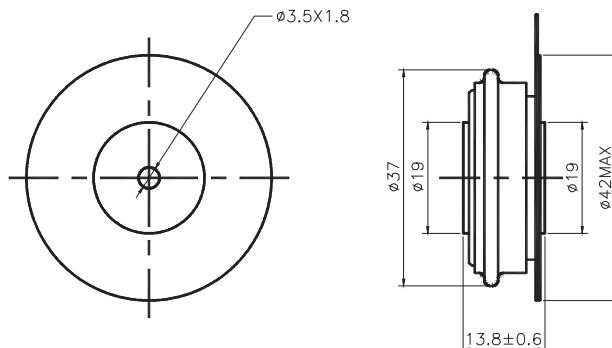
<http://www.zjxxdz1.com>

拟制	审核	核准
丁国盛	李园利	麻伟阳

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SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T_j (C)	VALUE			UNIT
				Min	Type	Max	
$I_{F(AV)}$	Mean forward current	180 half sinewave 50Hz Double side cooled, $\bar{R}_s=55\text{C}$	150			600	A
$I_{F(AV)}$	Mean forward current	180 half sinewave 50Hz Double side cooled, $\bar{R}_s=90\text{C}$	150			450	A
V_{RRM}	Repetitive peak reverse voltage	V_{RRM} tp=10ms $V_{RsM}= V_{RRM}+100\text{V}$	150	200		1000	V
I_{RRM}	Repetitive peak current	at V_{RRM}	150			16	mA
I_{FSM}	Surge forward current	10ms half sine wave $V_R=0.6V_{RRM}$	150			7.8	KA
$I^2T I$	^2T for fusing coordination					304 A	$\text{s}^2 \times 10^3$
V_{FO}	Threshold voltage		150			0.73	V
r_F	Forward slop resistance					0.68	$\text{m}\Omega$
V_{FM}	Peak on-state voltage I	$T_M=1500\text{A}, F=5.0\text{KN}$	150			1.75	V
I_{rm}	Reverse recovery current	$I_{TM}=600\text{A}, tp=1000\text{s},$ $di/dt=-40\text{A/s}, V_R=50\text{V}$	150			70	A
t_{rr}	Reverse recovery time					4.0	s
Q_{rr}	Recovery charge					140	C
$R_{th(j-h)}$	Thermal resistance Junction to heatsink	At 180° sine double side cooled Clamping force 5.0KN				0.090	C /W
F_m	Mounting force			3.3		5.5	KN
T_{stg}	Stored temperature			-40		160	C
W_t	Weight				50		g
Outline		ZT19aT					

Outline



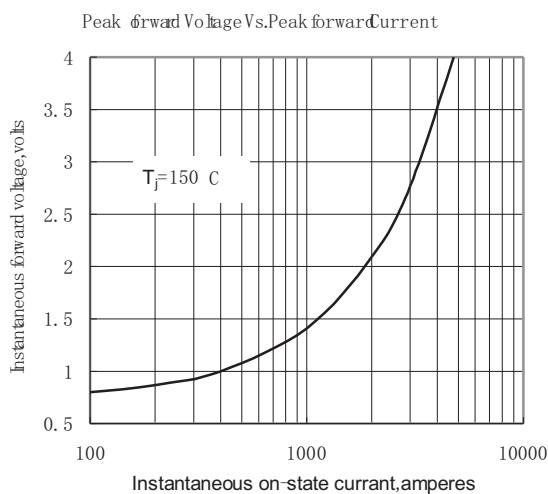


Fig. 1

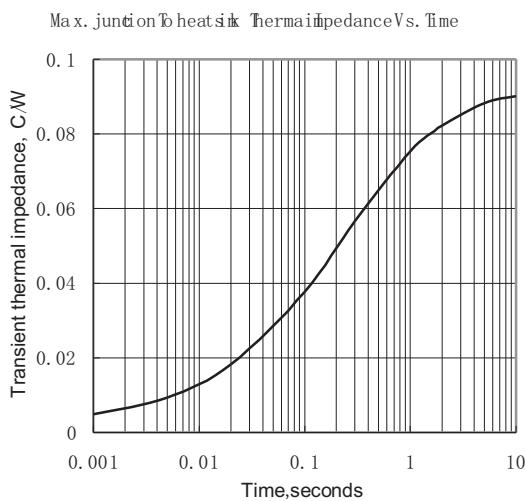


Fig. 2

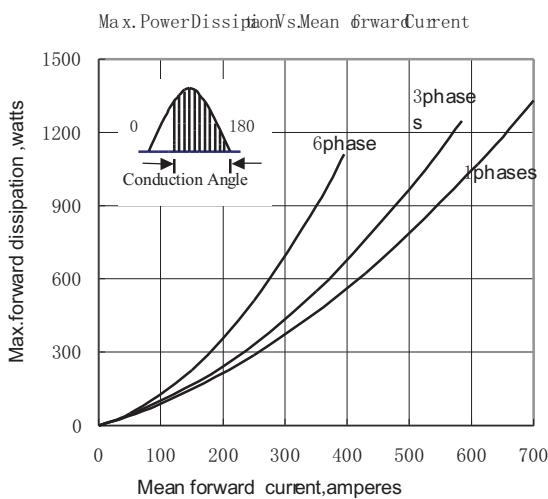


Fig. 3

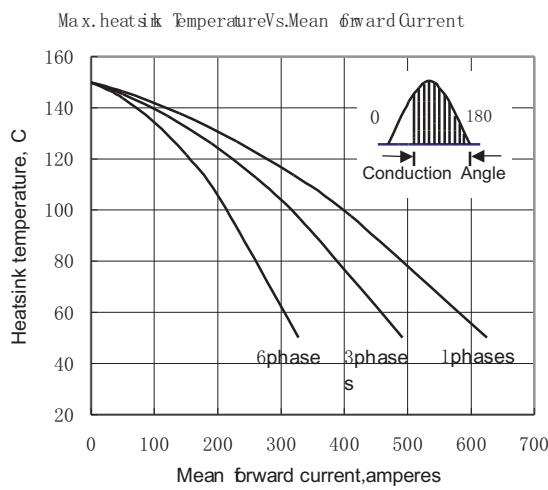


Fig. 4

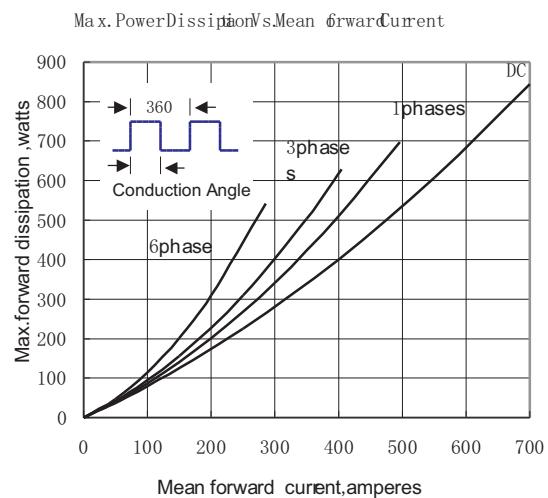


Fig. 5

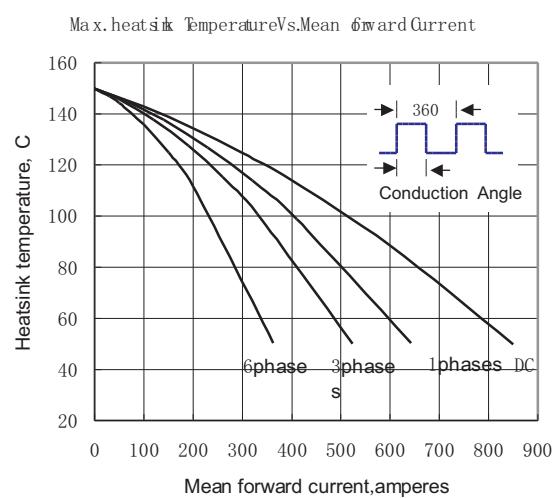


Fig. 6